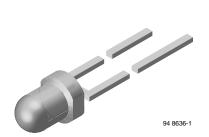
Vishay Semiconductors



Infrared Emitting Diode, RoHS Compliant, 950 nm, GaAs



TSUS4300 is an infrared, 950 nm emitting diode in GaAs

technology molded in a blue tinted plastic package.

FEATURES

- Package type: leaded
- Package form: T-1
- Dimensions (in mm): \oslash 3
- Peak wavelength: $\lambda_p = 950 \text{ nm}$
- High reliability
- Angle of half intensity: $\phi = \pm 16^{\circ}$
- · Low forward voltage
- Suitable for high pulse current operation
- · Good spectral matching with Si photodetectors
- · Package matches with detector TEFT4300
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

APPLICATIONS

- Infrared remote control and free air transmission systems with low forward voltage and small package requirements
- Emitter in transmissive sensors
- Emitter in reflective sensors

DESCRIPTION

PRODUCT SUMMARY				
COMPONENT	l _e (mW/sr)	φ (deg)	λ _P (nm)	t _r (ns)
TSUS4300	18	± 16	950	800

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
TSUS4300	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1

Note

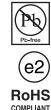
MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V _R	5	V
Forward current		I _F	100	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA
Surge forward current	t _p = 100 μs	I _{FSM}	2	А
Power dissipation		Pv	170	mW
Junction temperature		Tj	100	°C
Operating temperature range		T _{amb}	- 40 to + 85	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Soldering temperature	$t \leq$ 5 s, 2 mm from case	T _{sd}	260	°C
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	300	K/W

Note

Tamb = 25 °C, unless otherwise specified

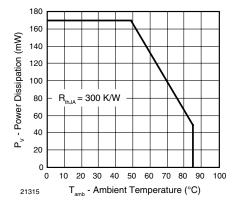
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TSUS4300

Infrared Emitting Diode, RoHS Compliant, Vishay Semiconductors 950 nm, GaAs



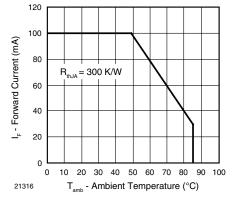


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERIST	ICS					
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 100 mA, t _p = 20 ms	V _F		1.3	1.7	V
	I _F = 1.5 A, t _p = 100 μs	V _F		2.2		V
Temperature coefficient of V_F	I _F = 100 mA	TK _{VF}		- 1.3		mV/K
Reverse current	V _R = 5 V	I _R			100	μA
Breakdown voltage	I _R = 100 μA	V _(BR)	5	40		
Junction capacitance	V _R = 0 V, f = 1 MHz, E = 0	Cj		30		pF
Radiant intensity	I _F = 100 mA, t _p = 20 ms	l _e	7	18	35	mW/sr
	I _F = 1.5 A, t _p = 100 μs	l _e		160		mW/sr
Radiant power	I _F = 100 mA, t _p = 20 ms	фе		20		mW
Temperature coefficient of ϕ_{e}	I _F = 20 mA	ΤKφ _e		- 0.8		%/K
Angle of half intensity		φ		± 16		deg
Peak wavelength	I _F = 100 mA	λρ		950		nm
Spectral bandwidth	I _F = 100 mA	Δλ		50		nm
Temperature coefficient of λ_p	I _F = 100 mA	ΤΚλρ		0.2		nm/K
Rise time	I _F = 100 mA	tr		800		ns
	I _F = 1.5 A	t _r		400		ns
Fall time	I _F = 100 mA	t _f		800		ns
	I _F = 1.5 A	t _f		400		ns
Virtual source diameter		d		2.1		mm

Note

 T_{amb} = 25 °C, unless otherwise specified

TSUS4300

Vishay Semiconductors Infrared Emitting Diode, RoHS Compliant, 950 nm, GaAs



BASIC CHARACTERISTICS

 $T_{amb} = 25 \ ^{\circ}C$, unless otherwise specified

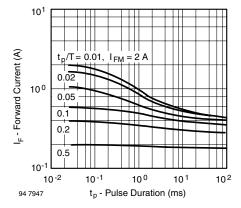


Fig. 3 - Pulse Forward Current vs. Pulse Duration

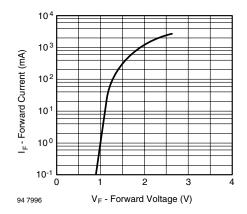


Fig. 4 - Forward Current vs. Forward Voltage

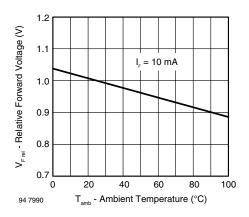


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

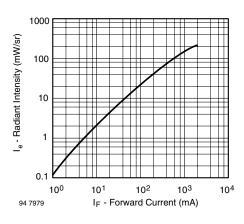


Fig. 6 - Radiant Intensity vs. Forward Current

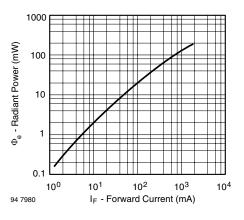


Fig. 7 - Radiant Power vs. Forward Current

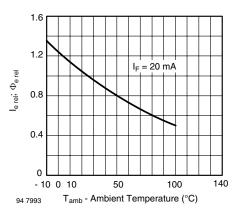


Fig. 8 - Relative Radiant Intensity/Power vs. Ambient Temperature



TSUS4300

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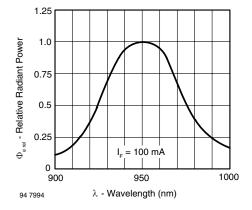
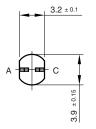
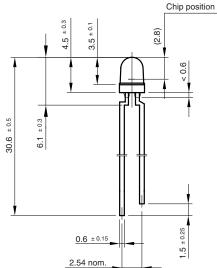
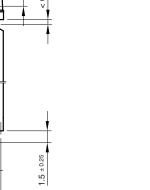


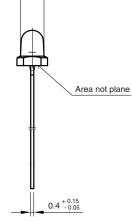
Fig. 9 - Relative Radiant Power vs. Wavelength

PACKAGE DIMENSIONS in millimeters







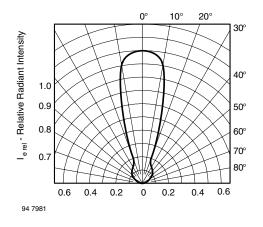


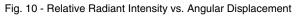
 3 ± 0.1



technical drawings according to DIN specifications









Vishay

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